

BC857CQBZ Datasheet



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DiGi Electronics Part Number BC857CQBZ-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BC857CQBZ

Description TRANS 45V 0.1A DFN1110D-3

Detailed Description Bipolar (BJT) Transistor 45 V 100 mA 340 mW Surfac

e Mount, Wettable Flank DFN1110D-3



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC857CQBZ	Nexperia USA Inc.
Series:	Product Status:
	Obsolete
Current - Collector (Ic) (Max):	Voltage - Collector Emitter Breakdown (Max):
100 mA	45 V
Vce Saturation (Max) @ lb, lc:	Current - Collector Cutoff (Max):
400mV @ 5mA, 100mA	15nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce:	Power - Max:
420 @ 2mA, 5V	340 mW
Operating Temperature:	Mounting Type:
150°C (TJ)	Surface Mount, Wettable Flank
Package / Case:	Supplier Device Package:
3-XDFN Exposed Pad	DFN1110D-3
Base Product Number:	
BC857	

Environmental & Export classification

8541.21.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	3 (168 Hours)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

1. General description

PNP general-purpose transistor in an ultra small DFN1110D-3 (SOT8015) leadless Surface-Mounted Device (SMD) plastic package with side-wettable flanks.

Table 1. Product overview

Type number	Package	NPN complement:	
	Nexperia	JEDEC	
BC857AQB	SOT8015	MO-340BA	BC847AQB
BC857BQB			BC847BQB
BC857CQB			BC847CQB

2. Features and benefits

- · High power dissipation capability
- Suitable for Automatic Optical Inspection (AOI) of solder joint
- · Smaller footprint compared to conventional leaded SMD packages
- Low package height of 0.5 mm
- AEC-Q101 qualified

3. Applications

- · General-purpose switching and amplification
- Space restricted applications

4. Quick reference data

Table 2. Quick reference data

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-45	V
I _C	collector current		-	-	-100	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	-	-200	mA
h _{FE}	DC current gain					
	BC857AQB	$V_{CE} = -5 \text{ V; } I_{C} = -2 \text{ mA}$	125	-	250	
	BC857BQB		220	-	475	
	BC857CQB		420	-	800	



5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base		C
2	E	emitter	3	В
3	С	collector		, h
			1 2	E sym132
			Transparent top view	

6. Ordering information

Table 4. Ordering information

Type number	Package	ckage					
	Name	Description	Version				
BC857AQB	DFN1110D-3	plastic leadless extremely thin small outline package with	SOT8015				
BC857BQB		side-wettable flanks (SWF); 3 terminals; 0.65 mm pitch; body: 1.1 mm x 1.0 mm x 0.48 mm					
BC857CQB	1	5004y. 1.1 mm x 1.0 mm x 0.40 mm					

7. Marking

Table 5. Marking

Type number	Marking code			
BC857AQB	A5			
BC857BQB	A6			
BC857CQB	A7			

8. Limiting values

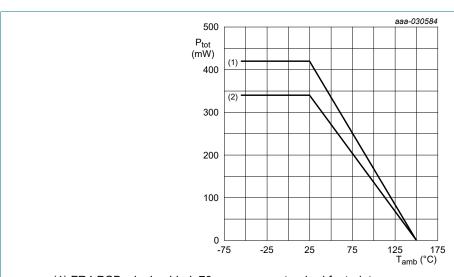
Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Conditions		Max	Unit
V _{CBO}	collector-base voltage	open emitter	open emitter		-50	V
V_{CEO}	collector-emitter voltage	open base		-	-45	V
V _{EBO}	emitter-base voltage	open collector		-	-6	V
I _C	collector current				-100	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	single pulse; t _p ≤ 1 ms		-200	mA
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms	single pulse; t _p ≤ 1 ms		-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	340	mW
			[2]	-	420	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature				150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided; 35 µm copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided; 70 µm copper; tin-plated and standard footprint.



- (1) FR4 PCB; single-sided; 70 μm copper, standard footprint
- (2) FR4 PCB; single-sided; 35 µm copper, standard footprint

Fig. 1. Power derating curves DFN1110D-3 (SOT8015)

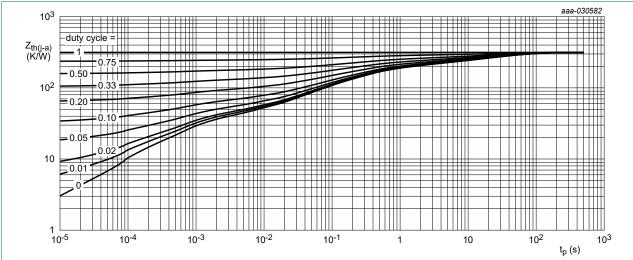
9. Thermal characteristics

Table 7. Thermal characteristics

 T_{amb} = 25 °C unless otherwise specified.

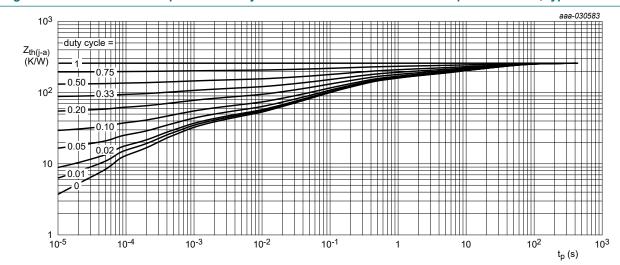
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	368	K/W
			[2]	-	-	298	K/W

- 1] Device mounted on an FR4 PCB; single-sided; 35 μm copper; tin-plated and standard footprint.
- 2] Device mounted on an FR4 PCB; single-sided; 70 µm copper; tin-plated and standard footprint.



FR4 PCB; single-sided; 35 µm copper, standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided; 70 µm copper, standard footprint

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

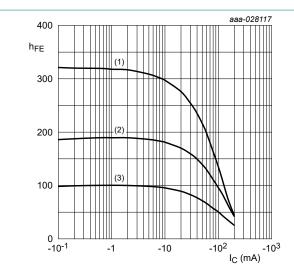
10. Characteristics

Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	I _C = -100 μA; I _E = 0 A		-50	-	-	V
V _{(BR)CES}	collector-emitter peak voltage	I _C = -2 mA; I _E = 0 A	I _C = -2 mA; I _E = 0 A		-	-	V
V _{(BR)EBO}	emitter-base breakdown voltage	I _E = -100 μA; I _C = 0 A		-6	-	-	V
I _{CBO}	collector-base cut-off	V _{CB} = -30 V; I _E = 0 A		-	-	-15	nA
	current	V _{CB} = -30 V; I _E = 0 A; T _j = 150 °C		-	-	-5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$		-	-	-100	nA
h _{FE}	DC current gain				'		
	BC857AQB	V _{CE} = -5 V; I _C = -2 mA		125	-	250	
BC857BQB				220	-	475	
	BC857CQB			420	-	800	
V _{CEsat} collector-emitter		I _C = -10 mA; I _B = -0.5 mA		-	-	-300	mV
	saturation voltage	I _C = -100 mA; I _B = -5 mA	[1]	-	-	-650	mV
V _{BE}	base-emitter voltage	$V_{CE} = -5 \text{ V} ; I_{C} = -2 \text{ mA}$	[2]	-600	-	-750	mV
		V _{CE} = -5 V ; I _C = -10 mA	[2]	-	-	-820	mV
V _{BEsat}	base-emitter saturation	I _C = -10 mA ; I _B = -0.5 mA		-	-700	-	mV
	voltage	I _C = -100 mA ; I _B = -5 mA	[1]	-	-850	-	mV
f _T	transition frequency			100	-	-	MHz
C _c	collector capacitance	V _{CB} = -10 V; I _E = i _e = 0 A; f = 1 MHz		-	2	-	pF
C _e	emitter capacitance	$V_{EB} = -0.5 \text{ V}; I_C = I_c = 0 \text{ A}; f = 1 \text{ MHz}$		-	10	-	pF
NF	noise figure	V_{CE} = -5 V; I_{C} = -200 μ A; R_{S} = 2 $k\Omega$; f = 1 kHz ; B = 200 Hz		-	-	10	dB

 $[\]begin{array}{ll} [1] & \text{pulsed; } t_p \leq 300 \ \mu\text{s; } \delta \leq 0.02 \\ [2] & V_{BE} \ \text{decreases by about 2 mV/K with increasing temperature.} \end{array}$



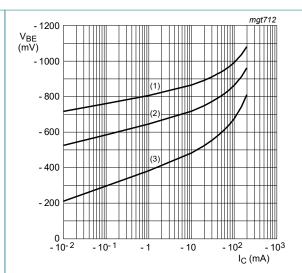
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. BC857AQB: DC current gain as a function of collector current; typical values



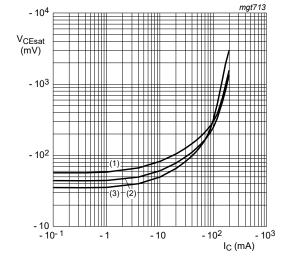
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb}$$
 = 150 °C

Fig. 5. BC857AQB: Base-emitter voltage as a function of collector current; typical values



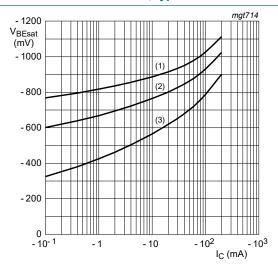
$$I_{\rm C}/I_{\rm B}$$
= 20

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 6. BC857AQB: Collector-emitter saturation voltage as a function of collector current; typical values



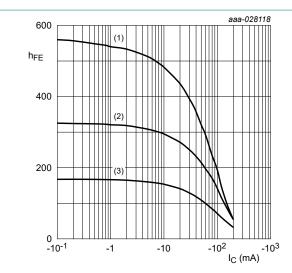
$$I_{\rm C}/I_{\rm B}=20$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

ig. 7. BC857AQB: Base-emitter saturation voltage as a function of collector current; typical values



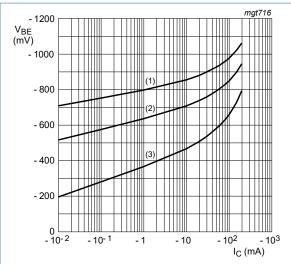
$$V_{CE}$$
 = -5 V

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

BC857BQB: DC current gain as a function of Fig. 8. collector current; typical values



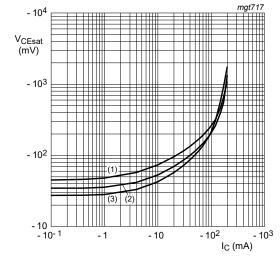
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

BC857BQB: Base-emitter voltage as a function Fig. 9. of collector current; typical values



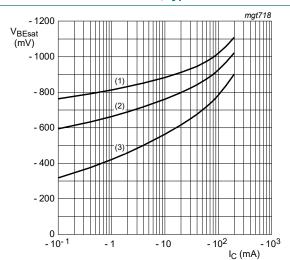
$$I_{C}/I_{B}=20$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

as a function of collector current; typical values



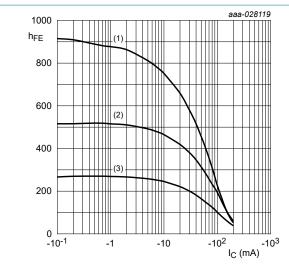
$$I_{\rm C}/I_{\rm B}=20$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 10. BC857BQB: Collector-emitter saturation voltage | Fig. 11. BC857BQB: Base-emitter saturation voltage as a function of collector current; typical values



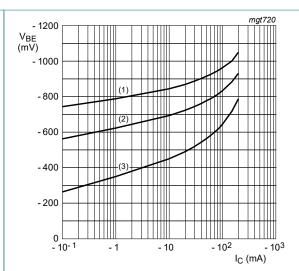
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 12. BC857CQB: DC current gain as a function of collector current; typical values



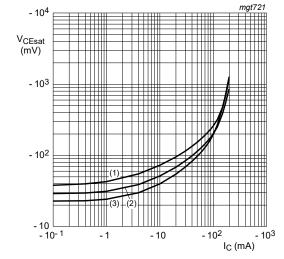
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 13. BC857CQB: Base-emitter voltage as a function of collector current; typical values

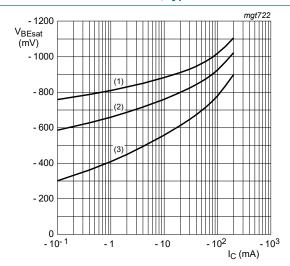


$$I_{C}/I_{B}=20$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B}$$
= 20

(1)
$$T_{amb} = -55$$
 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb}$$
 = 150 °C

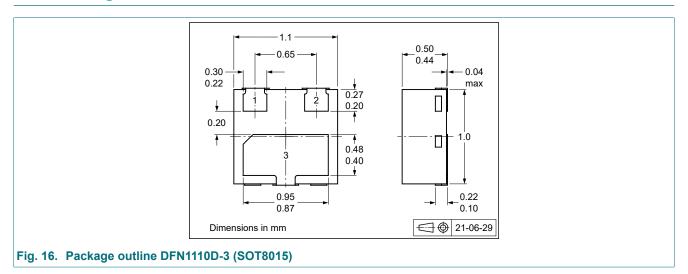
Fig. 14. BC857CQB: Collector-emitter saturation voltage | Fig. 15. BC857CQB: Base-emitter saturation voltage as a function of collector current; typical values

11. Test information

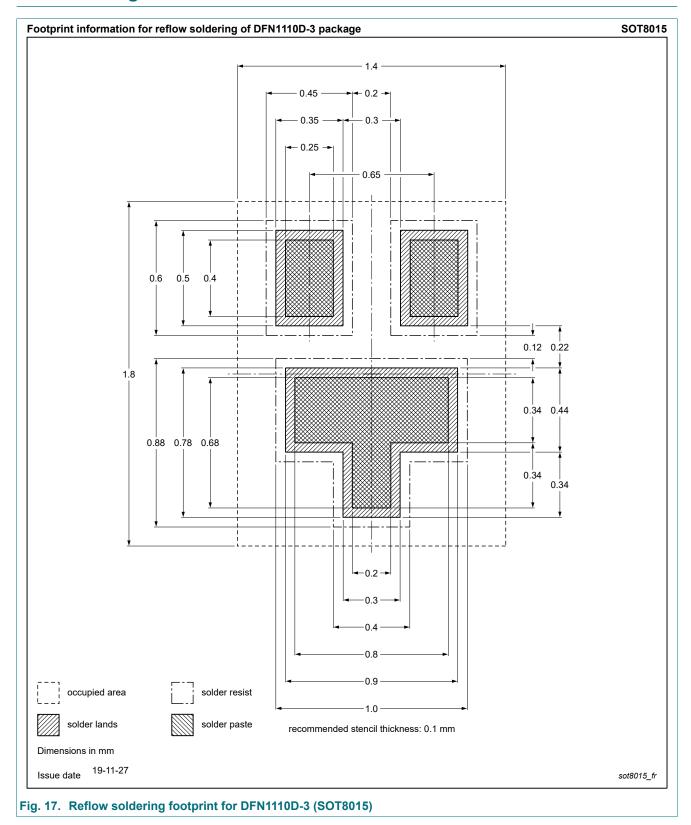
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

12. Package outline



13. Soldering



BC857xQB series

45 V, 100 mA PNP general-purpose transistor

14. Revision history

Table 9. Revision history

	,			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BC857XQB_SER v.4	20210920	Product data sheet	-	BC857XQB_SER v.3
Modifications:	Characteristics: C _e a	djusted		
BC857XQB_SER v.3	20210908	Product data sheet	-	BC857XQB_SER v.2
BC857XQB_SER v.2	20201209			BC857XQB_SER v.1
BC857XQB_SER v.1	20200427	Preliminary data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Nexperia

BC857xQB series

45 V, 100 mA PNP general-purpose transistor

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